ENHANCEMENT OF HIGH-FREQUENCY FIELD IN NEAR-IDEALMETAL MIXTURE

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Abstract

materials with small local loses. The possibility that 2D two-component system can have e ective absorption in the absence of local absorption was evidented [1]. We study the second and higher moments of electric eld and show that they diverge with the decrease of local absorption. he 3D system near the percolation threshold is also discussed. The oservation of giant eld uctuations in granular lm s rst discovered The 3D system near the pobservation of giant eld in [2] is explained.

Introduction

Recently [2] the e ect of giant a.c. eld uctuations in granular lm with sm all local absorption coe cient was discovered. This was dem on-strated by com puter sim ulations on a system, containing discrete ele-ments, capacitors and inductors, together with m easurements of eld distribution in a 2D m odel m etal-insulator m ixture.

distribution in a 2D m odel m etal-insulator m inture. The strong uctuations can be explained by the presence of global losses in the inhom ogeneous system, while the coe cients, determ ining the local losses are sm all [1], with a consequent local accumulation of electrom agnetic energy. In the electrotechnical language local energy accumulators are formed by random local L C circuits or using the solid state physics language, by local plasm on m odes. The presence of strong eld uctuations can be interpreted by poor convergence of e ective permeability of medium. This opposes to the usual convergency of e ective conductivity of random system. R egular fractals built from hierarchical im pedance chain were stud-ied in [3] and [4]. It was demonstrated that in these systems s both impedance [3] and the correlation radius [4] are fractal functions of fre-quency in the lossless limit. Such system s exhibit the divergency of

im pedance [3] and the correlation radius [4] are fractal functions of frequency in the lossless limit. Such system s exhibit the divergency of impedance when it size goes to in nity. The purpose of the present study is a theoretical explanation of the discovered e ect in the frame work of exactly solvable m odel of random m edia by D ykhne [1] and in a two-phase near ideal m etal-insulator 3D m odel near the percolation threshold. We shall show that if the real part of local conductivity falls down, the e ective rate of losses stays nite, resulting in the divergency of m oments of electrical eld m odulus higher than second power. We shall estimate the correlation length on a lossless m edium. This corresponds to the situation when the system can be transformed to one, contained the only local spots, resonating on be transformed to one, contained the only local spots, resonating on applied frequency, incorporated into m oderately inhom ogeneous m atrix.

Dykhne Medium

The problem of 2D statistically equivalent two-phase mixture was rst studied by A.D ykhne [1]. The e ective dielectric perm ittivity $"_{eff}$ in such medium obeys the law

$$"_{eff} = \frac{p_{1}}{1} \frac{p_{2}}{1};$$
 (1)

w here "1 and "2 are the local dielectric perm ittivities of both m edia. Let's consider the case of two m etal m edia such that on the frequency ! both m etals are near-lossless: eld

"_{1,2} = 1
$$\frac{\binom{2}{p}\binom{2}{(1,2)}}{!(!+\frac{1}{1,2})}$$
: (2)

We shall assume that the eld frequency lies between two plasm a frequencies $!_{p1}$ and $!_{p2}$, say $!_{p1} < ! < !_{p2}$, and ! 1. The last inequality tends to the sm all real part of conductivity = $\frac{1}{4}$ Im ". $= \frac{1}{4}$ Im

For bi-m etalm odel
$$_{(1;2)} = \frac{\frac{1}{p}(1;2)}{4!^2}$$
.

Such system may be considered, for example, as an in nite lattice, built from capacitors and inductors with impedances i=! C and i! L + r_0 , where C; L and r_0 are the capacitance, self-inductance and resistivity of elements, mixed in equal ratio. W ithin the region $!_{p1} < ! < !_{p2}$ both permittivities $_{1;2}$ are real, so lossless, while $_{eff}$ is im aginary. Nevertheless if the local rate of absorption is small, the system as a whole absorbs energy. The sign of "eff should be chosen positive in accordance with the condition of energy absorption. The imaginary con ict with the energy conservation law is resolved sim ilar to Landau damping | the absorp-tion of the whole media means the excitation of local plasm ons. That gives losses of a macroscopic media are gives losses of a means acroscopic medium while the microscopic media are lossless. Hence the energy should be absorbed by the whole medium without heating and should be accumulated by plasm ons up to it will convert to the heat by real conductivity.

In the case of Dykhne medium we can nd the exact form ulae for hTE $\dot{\textbf{j}}^2\, \dot{\textbf{i}}$ and hE $^2\, \dot{\textbf{i}}$. From the energy conservation law we have

$$_{eff} jhE ij^{2} = h jE j^{2} i; \qquad (3)$$

where $_{eff} = \frac{1}{4}$ Im " $_{eff}$. Dykhne [1] obtained the equations for mean even powers of eld modules in di erent phases of bi-m etalm edium

$${}^{n}_{1} h j E j^{2n} i_{1} = {}^{n}_{2} h j E j^{2n} i_{2}$$
(4)

(The subscripts 1 and 2 m eans that averaging is done in the st or second m edia correspondingly). The equation (4) m ay be generalized to the a.c. case including com plex conjugation and vector com ponents of eld (Appendix):

$$\sum_{i=2}^{n} \sum_{i=2}^{n-2} \sum_{i=1}^{n-2} \sum_{j=1}^{n-2} \left\{ z_{j} \right\}_{i=1}^{n-2} \left\{ z_{j} \right\}_{i=1}^{n-$$

The a.c. electric eld distribution is studied in a composite, containing Combining (3) and (5) for m = 1; n = 1 or m = 2; n = 0, we obtain

$$hjE j^{2}i = \frac{(1 + j''_{2} = "_{1}j) eff}{j''_{2} = "_{1}j + 2} jE ij^{2}$$
(6)

$$hE^{2}i = \frac{1}{2} "_{eff} \frac{"_{1} + "_{2}}{"_{1} "_{2}} hE^{2}i^{2}: \qquad (7)$$

The equations (3) and (6) show that hjE j^2 i diverges in a weakly absorblm sing m edium like reciprocal absorption, w hile hE² i rem ains nite. This divergency does not contradict to the nite value of average eld due to the phase shift of eld in di erent parts of system. The divergency of higher moments follows from the divergency of nite value of average eld due to

second m om ent and the Cauchy-Bunakovskii inequality

$$hjE j^{2n} i \quad hjE j^{2n} i$$
(8)

The equation (5) give the phase shifts between mean powers of in di erent media. In particular, the mean elds in the rst an second media have phase shift =2. elds rst and the

Correlation length of electric eld

The application of high frequency eld leads to appearance of "hot" spots, resonantly accumulating the energy. The spatial distribution of them is random and depends on the frequency. From that point of view any medium containing regions with both positive and negative permittivities can be transformed to rare gas of hot spots, incorporated into a weakly inhom ogeneous m atrix.

In the fram ework of L-C m odel the electric circuit has one resonant frequency per a cell. A ll of them are distributed within the range ! $!_{\,p\,1}\,.$ The typical width of resonance is determ ined by $% (p\,)$. Thus the density of resonances per unite frequency interval is = (! p2 !_{p1}) and the mean distance between them grows like

$$((!_{p2} !_{p1}) =)^{1=2}$$
: (9)

This is a speci c correlation length of electric eld. From the other hand, we can use the "hot spots" language. Let's change the system to a 2D system, containing round inclusions with radius a and perm ittivity "2 into a matrix with perm ittivity "1. The low density approximation give

$$E = hE i + \frac{p_n (r r_n)}{(r r_n)^2}$$
(10)

$$= E(r_n);$$
 (11)

where = $\frac{"1 "2}{"1 + "2} \frac{a^2}{2}$ is the polarizability of inclusions. If is not too large we can substitute hE i instead of E (rn). The e ective perm ittivity in this model is

рn

$$"_{eff} = "_1 (1 + 4 n);$$
 (12)

where n is the density of inclusions. The polarizability of inclusions diverges if $"_1 + "_2 = 0$, which corresponds to a local plasm on m ode. We can estim ate the correlator of potential uctuations ' (r) as

$$L = \frac{2}{(p (r - r^{0}))} \frac{(p r^{0})}{(r - r^{0})^{2}} \frac{(p r^{0})}{r^{0}} dr^{0} = n (hEi)^{2} \log \frac{R}{r} : (13)$$

R is a cuto radius, included to \lim it the divergency of integral in (13). The correlation length can be estimated from (13) as a length scale, where the uctuating potential is comparable with the potential of avwhere the uctuater of the second seco erage

$$L_c$$
 $(n^2)^{1=2} \log \frac{n^2}{a}$: (14)

Really if the eld uctuations exceed the average eld hE i we cannot consider the polarization p as a preassigned quantity and should change it together with the electric eld. Hence L_c plays role of limiting size for the form ula (13) and R = L_c . The density of inclusions n in D ykhnemedium can be estimated as a density of "hot spots" n = $\frac{1}{|p_2|!p_1|!}$. The substitution of this value to (14) give the form ula (9) with the accuracy of logarithm. eld hE i we cannot

From the form ula (6) it follows that hjE j^2 i grows like 1= and the

1=2 . This shows a distance between hot spots grows proportionally $^{1=2}$. This shows a good agreem ent with the experim ental results and com puter sim ulations [2].

[2]. The ultimate "hot spots" language does not correspond to the power-law correlation of electric eld. Nevertheless if permits to es-timate the correlation length in the a.c. problem. The question about correlation length of electric eld is not so sim-

ple. The question about correlation length of electric fear is not so sum-property, lim iting the power behavior of probability of two distant sites to belong to the same cluster. It is independent on electric parameters. From the other hand in the static conductivity (or dielectric re-sponse) problem the correlation length in the smearing dom ain is deter-mined by the spatial size where the opportunity of current to ow in both media is equal and both phases give the same constrbutions to the both m edia is equal and both phases give the sam e contributions to the

both media is equal a both phases give the same contract that is a contract of the end of the same contract of stationary case. In the resonant case w ithout local losses the correlation length is in nite.

length is n nite. In such system the response should depend on a speci c realiza-tion of medium. The spatial distribution of eld become s fractal and the electric properties are not self-averaging. For example, this is re ecting in the frequency dependence of correlation radius (4). The system spec-trum contains separate lines. This is easy to understand if to consider the lossless system like the quantum particle (photon) propagation in the inhom ogeneous disordered medium. In fact, the spectrum of quan-tum system consists from distinct lines and the spatial distribution of wave function am plitude is fractal. The divergency of squared module of electric eld corresponds to the localization of photons. In the terms of L-C model this is the localization of eld in resonating circuits. The nite real part of conductivity lim its the divergency of eld and the correlation radius but retains the com plicated structure of eld.

Higher dim ensions

Unlike 2D case there is no exact solution for e ective coe cients in the 3D system, but the percolation theory gives the e ective constants for the strongly inhom ogeneous m edium lim it.

The strongly innom operations of the binary mixture is near the percolation threshold, while both permittivities are nite, the e ective permittivity does not depend on the concentration but on the ratio of permittivities is small, $\frac{n_1}{n_2} = h$ 1, a power dependence is valid

$$"_{eff} = "_2 h$$
 : (15)

The value of h is sm all, if $!_{p1} = !_{p2}$ and $!_{p1} < ! < !_{p2}$. Above the percolation threshold (> 0) the width of sm earing

domain is < h =t

domain is 'h'... These estim ations are usually applied to describe the system with positive conductivities (dielectric constants). The analyticity permits to continue them for the negative signs of constants too. The equation (15) tends to the com plexity of e ective permittivity in the mixture of domains with positive and negative permittivities. The phase of "eff is universal and is determined by a critical exponent only:

$$A rg''_{eff} = (2n + 1) + :$$
 (16)

A nalogously D ykhnem edium, the root branch n = 0 can be chosen if one account for the absence of perm ittivity discontinuities in the complex plane except for the negative part of abscissa.

Like 2D, the small local losses may be accompanied by the nite e ective rate of absorption. Instead of the equation (3) we can use the inequalities for the mean square of eld. Using [5], we obtain the inequalities

$$h \stackrel{1}{-} i_{eff} j h E i j^{2} > h j E j^{2} i > \frac{eff}{h} j h E i j^{2} : \qquad (17)$$

The formula (17) shows that mean square of eld also diverges. The rate of divergency can be estimated if we assume that both media have the same conductivities = 1 = 2, when the inequalities $_1 = _2$, when the inequalitie convert to the equation

$$hjE j^{2}i = -\frac{eff}{j}hE ij^{2}:$$
(18)

The last equation coincides with the consequence of Eq. 3 in 2D case with the sam e assum ptions.

Conclusions

In the present work we studied the moments of electric eld in the more present with low absorption. We exactly found the second moments and showed that h $\beta \epsilon f^2$ i diverges and h $\epsilon^2 i$ is limited if the absorption goes down. We couldn't and higher moments but proved the nd higher m om ents but proved the

relation between mean values or $j \in j$ in two materials and the alvergency of the higherm nom ents $h \not \in \hat{J}^n$ i. The divergency is conditioned by the di erent signs of media permitivities responsible for the existance of local plasm ons. The divergency of eld moments is not speci to for 2D 2 -components composite only. The same result is obtained for 3D system in the sm earing dom ain.

The divergency of higher m om ents leads to the divergency of eld correlation length in the system with low local absorption. U sually the system is described by the e ective permittivity or the e ective conduc-tivity which have small uctuations in a large system. This therm ody-nam ic lim it requires smallness of the correlation length compared to the system size and hence nite absorption. If this length exceeds the size of the system the orective promotion do not have do not be in the and they the system the elective properties do not have de nite im its and they have fractal dependencies on system size. This is the behavior evidenced in regular fractal circuits [4]. We should underline the di erence of static and a.c. cases. In the

static case the correlation length is determ ined by the ratio of dielec-tric constants or conductivities of m edia. In the high-frequency case the correlation length is not connected with the absolute values of perm intivities but with the small conductivity, detem ining the absorption. If we consider the case of ideal conductors or insulators with zero absorp-tion, the statice ective dielectric constant and conductivity are de nite quantities, while in the a.c. case they are not. This conclusion becomes alm ost trivial if we consider the static properties of mixture with positive and negative conductors, being for-nally equivalent to the metalm ixture with alternating signs of permit-

tivities. The m ixture with negative conductors is therm odynam ically unstable. This means the generation of a.c. and no therm odynam ic lim it.

A cknow ledgm ents

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Appendix. The relation between eld m om ents.

To obtain the relation (5) we can do Dykhne transform with the $\;$ eld and the electric displacem ent D = "E

$$E^{0} = 1 = "_{eff} [n D];$$
 $D^{0} = "_{eff} [n E];$ (19)
x ! y; y ! x:

where " = $"_{1;2}$ in the second medium correspondingly. It conserves the equations for eld and displacem ent

r D = 0	r	E = 0;	(20)
$r D^{0} = 0$	r	$E^{0} = 0$	

and transform s the expression for electric displacem ent D $\,=\,$ "E to D 0 = $\frac{"}{"_{eff}} E^0$. U sing the statistical equivalence of both m edia, we obtain (5).

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